

**Notice of References Cited**

Application/Control No.

09/496,506

Applicant(s)/Patent Under  
Reexamination  
NAYFEH ET AL.

Examiner

Sara W. Cran

Art\*Unit

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Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number	Date	Name	Classification	
		Country Code-Number-Kind Code	MM-YYYY			
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	B	US-5,932,889	08-1999	Matsumura et al.	257	14
	C	US-				
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	F	US-				
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	I	US-				
	J	US-				
	K	US-				
	L	US-				
	M	US-				

**FOREIGN PATENT DOCUMENTS**

*		Document Number	Date	Country	Name	Classification	
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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Tiware, S., et al., "A silicon nanocrystals based memory," Appl. Phys. Lett. 68(10), 4 March 1996, pp 1377-79.
	V	
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	X	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.